## **ELECTRICAL CHARACTERISTICS**

Part Number	Working Voltage (Vw)	Breakdown Voltage (Vb)	Clamping Voltage (Vc)	Peak Current (Ip)	Transient Energy (Et)	Typical Capacitance (C)	
	Volt	Volt	Volt	Amp	Joule	pF	
	<50 μ A	1mA(DC)	2.5A,8/20 $\mu$ s	8/20 $\mu$ s	10/1000 $\mu$ s	1KHz	1MHz
JMV0805S090T781	9.0	10.0~15.0	27	40	0.1	780	-

- Vw- The max. steady state DC operating voltage of which varistor could maintain also not exceeding 50uA leakage current.
- Vb- The Voltage acrossed the device measured at 1mA DC current.
- Vc- The peak voltage acrossed the varistor measured at a specified pulse current and waveform.
- Ip- The max.peak current applied with specified wavefoem without any possibility of device fail.
- Et- The max. energy which dissipated with the specified waveform without any possibility of device fail.
- C The device capacitance measured with zero volt bias, 1.0Vrms and 1KHz / 0.5 V rms and 1 MHz.

MLV Storage condition → Temperature: ≤30°C / Humidity : ≤60% RH(Moisture Sensitivity Levels: 2a)

MLV Preservation period → 6 months

## **External Dimension**

Chip Dimension

	)	inch(mm)		<u> </u>		
Chip Size	L	W	Т	Α	w	
0805 (2012)	0.079±0.008 (2.01±0.20)	0.049±0.008 (1.25±0.20)	0.04max. (1.02max.)	0.028max. (0.71max.)	Т	
					<b>←→</b>	